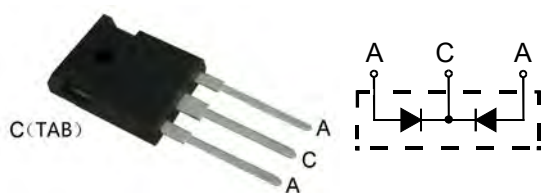


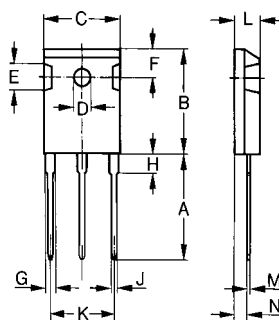
HUR4020PT

Soft Recovery Behaviour High-Performance Wide Temperature Range Ultra Fast Recovery Epitaxial Diodes



A=Anode, C=Cathode, TAB=Cathode

Dimensions TO-247AD



Dim.	Millimeter		Inches	
	Min.	Max.	Min.	Max.
A	19.81	20.32	0.780	0.800
B	20.80	21.46	0.819	0.845
C	15.75	16.26	0.610	0.640
D	3.55	3.65	0.140	0.144
E	4.32	5.49	0.170	0.216
F	5.4	6.2	0.212	0.244
G	1.65	2.13	0.065	0.084
H	-	4.5	-	0.177
J	1.0	1.4	0.040	0.055
K	10.8	11.0	0.426	0.433
L	4.7	5.3	0.185	0.209
M	0.4	0.8	0.016	0.031
N	1.5	2.49	0.087	0.102

	V_{RSM}	V_{RRM}
	V	V
HUR4020PT	200	200

Symbol	Test Conditions	Maximum Ratings	Unit
I_{FAVM}	$T_C=135^{\circ}C$; rectangular, $d=0.5$ Per device Per diode	40 20	A
I_{FSM}	$T_{VJ}=45^{\circ}C$; $t_p=10ms$ (50Hz), sine	220	A
E_{AS}	$T_{VJ}=25^{\circ}C$; non-repetitive; $I_{AS}=2.5A$; $L=180\mu H$	0.8	mJ
I_{AR}	$V_A=1.5 \cdot V_R$ typ.; $f=10kHz$; repetitive	0.3	A
T_{VJ} T_{VJM} T_{stg}		-55...+175 175 -55...+150	$^{\circ}C$
P_{tot}	$T_C=25^{\circ}C$	105	W
M_d	mounting torque	0.4...0.6	Nm
Weight	typical	6	g

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Symbol	Test Conditions	Characteristic Values		Unit
		typ.	max.	
I_R	$T_{VJ}=25^{\circ}\text{C}; V_R=V_{RRM}$		10	uA
	$T_{VJ}=150^{\circ}\text{C}; V_R=V_{RRM}$		0.5	mA
V_F	$I_F=20\text{A}; T_{VJ}=25^{\circ}\text{C}$	0.95	1.05	V
	$I_F=20\text{A}; T_{VJ}=150^{\circ}\text{C}$		1.00	
R_{thJC} R_{thCH}		0.35	1.0	K/W
t_{rr}	$I_F=1\text{A}; -di/dt=100\text{A/us}; V_R=30\text{V}; T_{VJ}=25^{\circ}\text{C}$	20		ns
I_{RM}	$V_R=100\text{V}; I_F=20\text{A}; -di_F/dt=100\text{A/us}; T_{VJ}=100^{\circ}\text{C}$		2.7	A

FEATURES

- * International standard package
- * Planar passivated chips
- * Very short recovery time
- * Extremely low switching losses
- * Low I_{RM}-values
- * Soft recovery behaviour
- * RoHS compliant

APPLICATIONS

- * Antiparallel diode for high frequency switching devices
- * Antisaturation diode
- * Snubber diode
- * Free wheeling diode in converters and motor control circuits
- * Rectifiers in switch mode power supplies (SMPS)
- * Inductive heating
- * Uninterruptible power supplies (UPS)
- * Ultrasonic cleaners and welders

ADVANTAGES

- * Avalanche voltage rated for reliable operation
- * Soft reverse recovery for low EMI/RFI
- * Low I_{RM} reduces:
 - Power dissipation within the diode
 - Turn-on loss in the commutating switch

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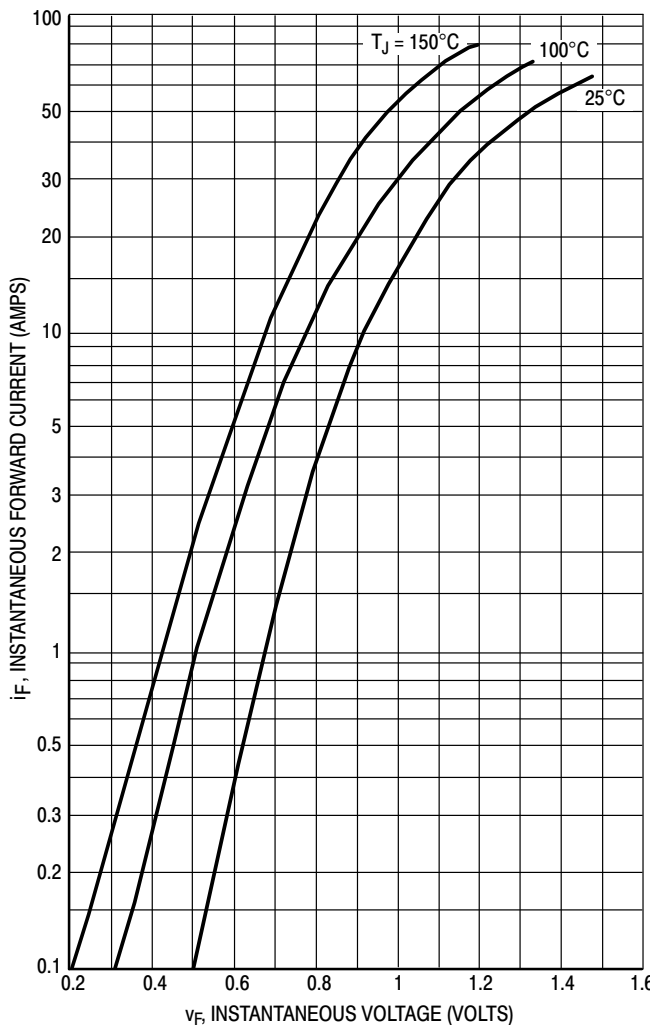


Figure 1. Typical Forward Voltage (Per Leg)

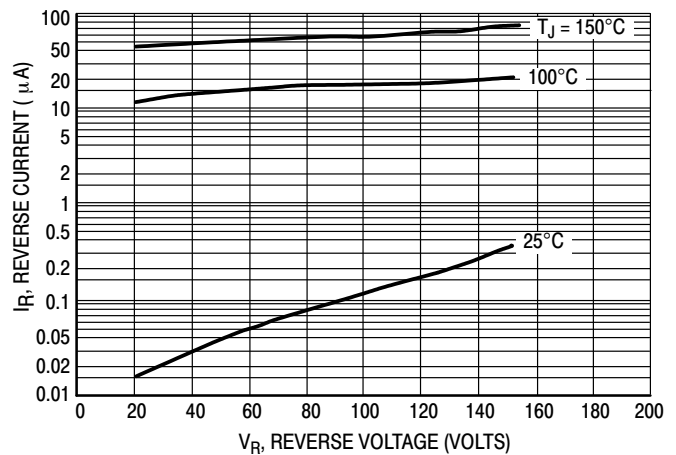


Figure 2. Typical Reverse Current (Per Leg)

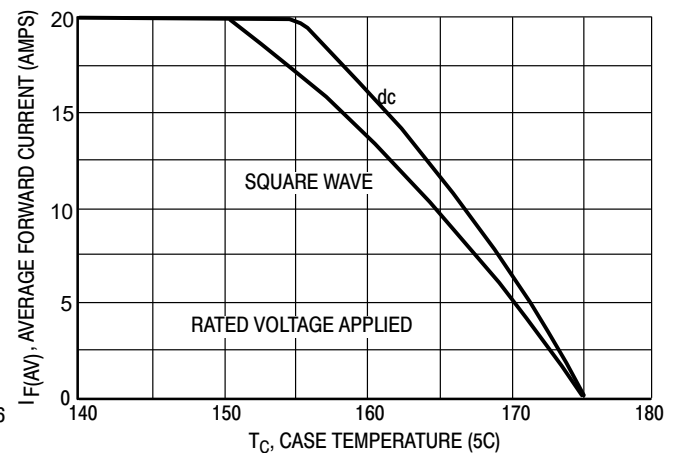


Figure 3. Current Derating, Case (Per Leg)

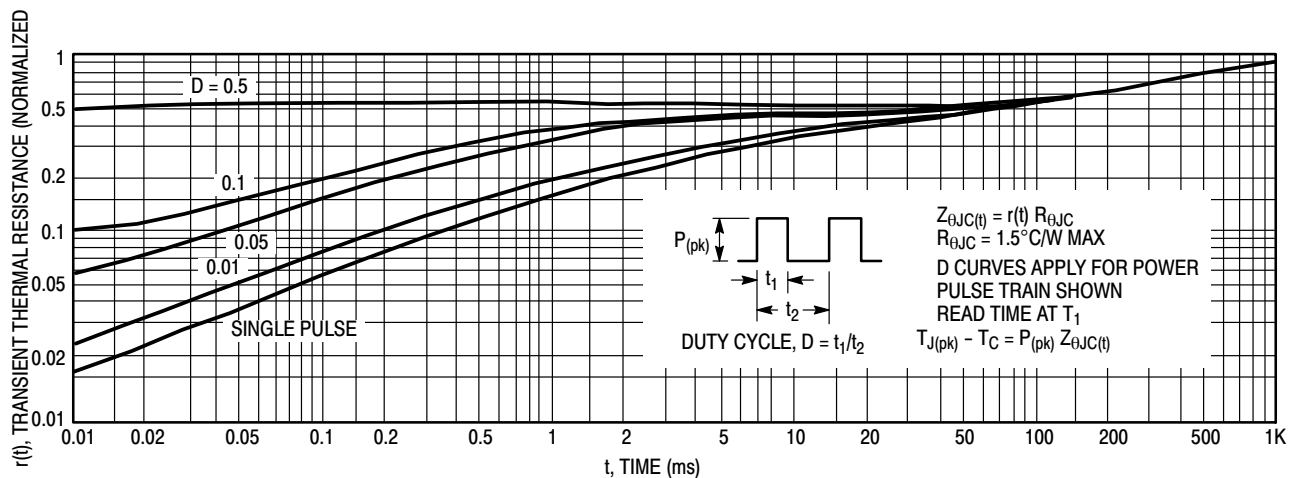


Figure 4. Thermal Response

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